

Electronic Filing System (EFS) Data Electronic Patent Application Submission USPTO Use Only

EFS ID:

60114

Application ID:

10647925

Title of Invention:

High-Voltage Transistor With

Buried Conduction Layer

First Named Inventor:

Donald Disney

Domestic/Foreign Application:

Domestic Application

Filing Date:

2003-08-26

Effective Receipt Date:

2004-04-29

Submission Type:

Information Disclosure

Statement

Filing Type:

Confirmation number:

2438

Attorney Docket Number:

03692.P054D2

Total Fees Authorized:

Digital Certificate Holder: cn=Bradley John Bereznak,ou=Registered Attorneys,ou=Patent and

Trademark Office,ou=Department of Commerce,o=U.S. Government,c=US Certificate Message Digest: 6ebf4406b0db5b64cdb51e4a5cd4814b1d404787

APR 2 9 2004

TRANSMITTAL

芒lectronic Version v1.1 Stylesheet Version v1.1.0

Title of Invention

High-Voltage Transistor With Buried Conduction Layer

Application Number:

10/647925

Date:

2003-08-26

First Named Applicant:

Donald Ray Disney

Confirmation Number:

2438

Attorney Docket Number: 03692.P054D2

I hereby certify that the use of this system is for OFFICIAL correspondence between patent applicants or their representatives and the USPTO. Fraudulent or other use besides the filing of official correspondence by authorized parties is strictly prohibited, and subject to a fine and/or imprisonment under applicable law.

I, the undersigned, certify that I have viewed a display of document(s) being electronically submitted to the United States Patent and Trademark Office, using either the USPTO provided style sheet or software, and that this is the document(s) I intend for initiation or further prosecution of a patent application noted in the submission. This document(s) will become part of the official electronic record at the USPTO.

Submitted by:	Elec. Sign.	Sign. Capacity	
Bradley J. Bereznak Registered Number: 33,474	ВЈВ	Attorney	

Documents being submitted

Files

us-ids

03692.P054D2-usidst.xml

us-ids.dtd

us-ids.xsl

Comments



ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18 Stylesheet Version v18.0

> Title of Invention

High-Voltage Transistor With Buried Conduction Layer

Application Number:

10/647925

Confirmation Number:

2438

First Named Applicant:

Donald Disney

Attorney Docket Number: 03692.P054D2

Art Unit:

2811

Examiner:

Steven Ho Yin Loke

Search string:

(5146298 or 5155574 or 6184555 or 6168983 or 6207994 or 4618541 or 4665426 or 4890146 or 4922327 or 5386136 or 5894154 or 4626879 or 4754310 or 4764800 or 4811075 or 4926074 or 4963951 or 5010024 or 5025296 or 5040045 or 5068700 or 5237193 or 5258636 or 5270264 or 4939951 or 4967246 or 5313082 or 5637898

or 5654206 or 5656543 or 5659201 or 5663599 or 5716887 or 5324683 or 5349225 or 5359221 or 5411901 or 5521105 or 5550405 or 5670828

or 5679608 or 5943959 or 6010926 or

5998833).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	5146298	1992-09-08	Eklund			
	2	5155574	1992-10-13	Yamaguchi			
	3	6184555	2001-02-06	Tihanyi et al.	B1		
	4	6168983	2001-01-02	Rumennik et al.	B1		
	5	6207994	2001-03-27	Rumennik et al.	B1		
	6	4618541	1986-10-21	Forouhi et al.			
	7	4665426	1987-05-12	Allen et al.			
	8	4890146	1989-12-26	Williams et al.			
	9	4922327	1990-05-01	Mena et al.			
	10	5386136	1995-01-31	Williams et al.	1		

11	5894154	1999-04-13	Shibib		
12	4626879	1986-12-02	Colak Coe		
13	4754310	1988-06-28			
14	4764800	1988-08-16	Sander		
15	4811075	1989-03-07	Eklund		
16	4926074	1990-07-03	Singer et al.		
. 17	4963951	1990-10-10	Adler et al.		
18	5010024	1991-04-23	Allen et al.		
19	5025296	1991-06-18	Fullerton et al.		
20	5040045	1991-08-13	McArthur et al.		
21	5068700	1991-11-26	Yamaguchi et al.		
· 22	5237193	1993-08-17	Williams et al.		
23	5258636	1993-11-02	Rumennik et al.		
24	5270264	1993-12-14	Andideh et al.		
25	4939951	1990-07-03	Singer et al.		
26	4967246	1990-10-30	Tanka		
27	5313082	1994-05-17	Eklund		
28	5637898	1997-06-10	Baliga		
29	5654206	1997-08-05	Merrill		
30	5656543	1997-08-12	Chung		
31	5659201	1997-08-19	Wollesen		
32	5663599	1997-09-02	Lur		
33	5716887	1998-02-10	Kim		
34	5324683	1994-06-28	Fitch et al.		
35	5349225	1994-09-20	Redwine et al.		
36	5359221	1994-10-25	Miyamoto et al.		
37	5411901	1995-05-01	Grabowski et al.		
38	5521105	1996-05-28	Hsu et al.		
39	5550405	1996-08-27	Cheung et al.		
40	5670828	1997-09-23	Cheung et al.		
41	5679608	1997-10-21	Cheung et al.		
42	5943959	1999-08-24	Akiyama et al.		
43	6010926	2000-01-04	Rho et al.		
44	5998833	1999-12-07	Baliga		

Signature

li	
Ш	